

## RBV1000D - RBV1010D

**PRV : 50 - 1000 Volts**

**Io : 10 Amperes**

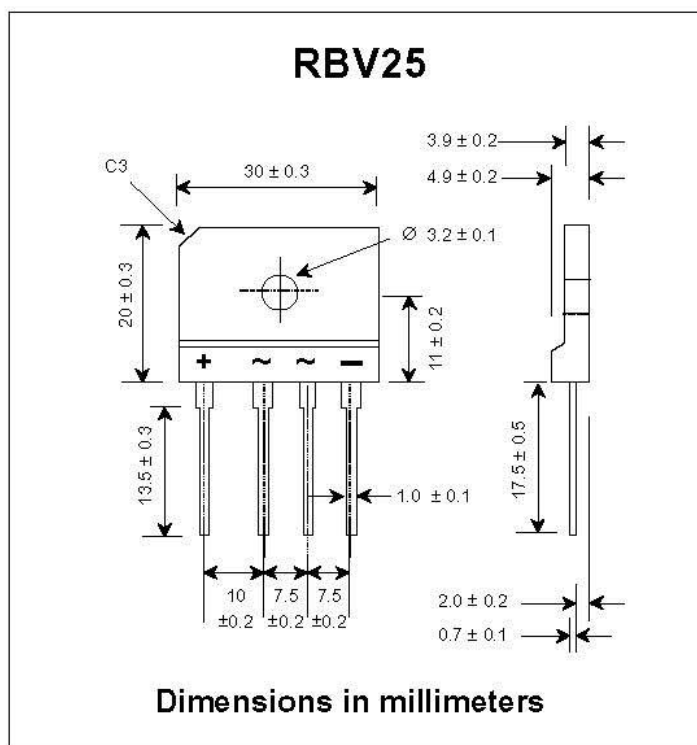
### FEATURES :

- \* High current capability
- \* High surge current capability
- \* High reliability
- \* Low reverse current
- \* Low forward voltage drop
- \* High case dielectric strength of 2000 V<sub>DC</sub>
- \* Ideal for printed circuit board
- \* Very good heat dissipation

### MECHANICAL DATA :

- \* Case : Reliable low cost construction utilizing molded plastic technique
- \* Epoxy : UL94V-0 rate flame retardant
- \* Terminals : Plated lead solderable per MIL-STD-202, Method 208 guaranteed
- \* Polarity : Polarity symbols marked on case
- \* Mounting position : Any
- \* Weight : 7.7 grams

## SILICON BRIDGE RECTIFIERS



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

RATING	SYMBOL	RBV 1000D	RBV 1001D	RBV 1002D	RBV 1004D	RBV 1006D	RBV 1008D	RBV 1010D	UNIT
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum Average Forward Current T <sub>c</sub> = 55°C	I <sub>F(AV)</sub>	10							A
Peak Forward Surge Current Single half sine wave Superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	300							A
Current Squared Time at t < 8.3 ms.	I <sup>2</sup> t	168							A <sup>2</sup> S
Maximum Forward Voltage per Diode at I <sub>F</sub> = 10 A	V <sub>F</sub>	1.0							V
Maximum DC Reverse Current Ta = 25 °C at Rated DC Blocking Voltage Ta = 100 °C	I <sub>R</sub>	10							μA
	I <sub>R(H)</sub>	200							μA
Typical Thermal Resistance (Note 1)	RθJC	2.2							°C/W
Operating Junction Temperature Range	T <sub>J</sub>	- 40 to + 150							°C
Storage Temperature Range	T <sub>STG</sub>	- 40 to + 150							°C

#### Notes :

1. Thermal Resistance from junction to case with units mounted on a 3.2" x 3.2" x 0.12" (8.2cm x 8.2cm x 0.3cm.) Al.-Finned Plate.

## RATING AND CHARACTERISTIC CURVES (RBV1000D - RBV1010D)

FIG.1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

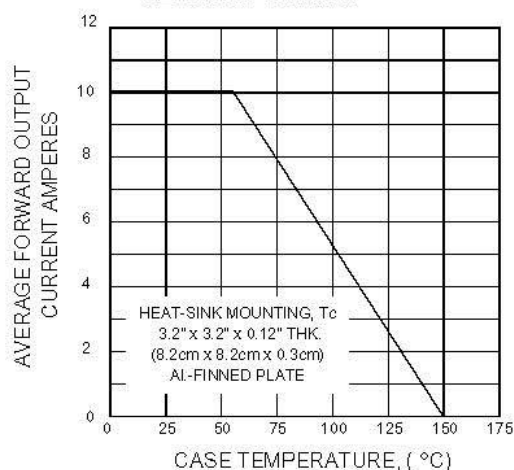


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

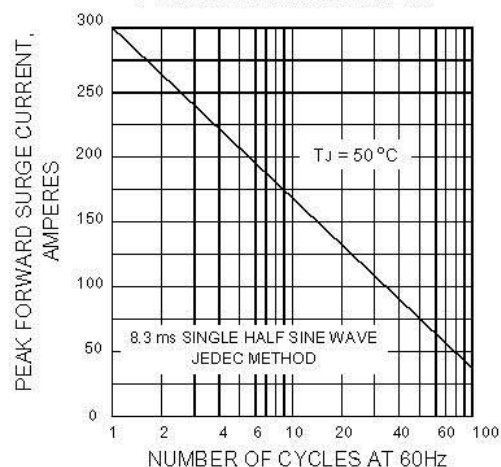


FIG.3 - TYPICAL FORWARD CHARACTERISTICS PER DIODE

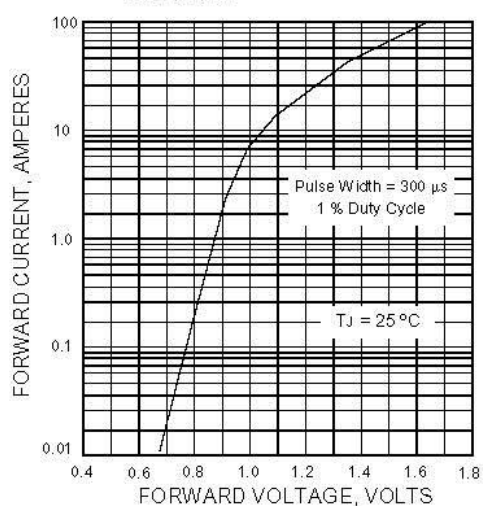


FIG.4 - TYPICAL REVERSE CHARACTERISTICS PER DIODE

